2-input NOR Gate

HITACHI

ADE-205-015A(Z) 2nd Edition August 1993

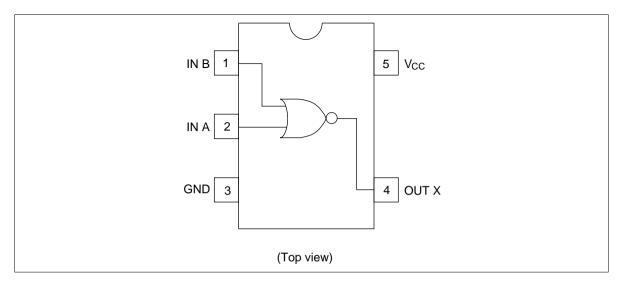
Description

The HD74UH02 is high speed CMOS two input NOR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

Features

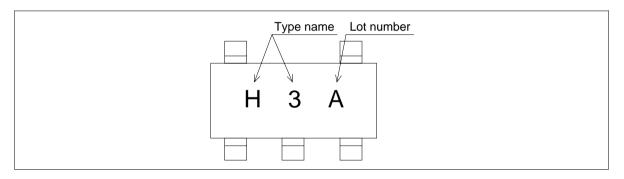
- Encapsulated in very small 5pins package of $2.9 \times 1.6 \times 1.1$ mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as hitachi uni logic series.
- Supplied on embos taping for high speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC02 Supply voltage range: 2 to 6 V Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$

Pin Arrangement





Article Indication



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit		
Supply voltage	V _{cc}	-0.5 to +7.0	V		
Input voltage	V _{IN}	–0.5 to V _{cc} +0.5	V		
Output voltage	V _{OUT}	–0.5 to V _{cc} +0.5	V		
Input diode current	I _{IK}	±20	mA		
Output diode current	Ι _{οκ}	±20	mA		
Output current	I _{OUT}	±25	mA		
V _{cc} /GND current	I _{CC} , I _{GND}	±25	mA		
Power dissipation	P _T	200	mW		
Strage temperature	Tstg	–65 to +150	°C		

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	
Supply voltage	V _{cc}	2 to 6	V	
Input voltage	V _{IN}	0 to V _{cc}	V	
Output voltage	V _{OUT}	0 to V _{cc}	V	
Operating temperature	Topr	-40 to +85	°C	
Input rise/fall time	t _r , t _f	0 to 1000 (V_{cc} = 2.0 V)	ns	
		0 to 500 (V_{cc} = 4.5 V)		
		0 to 400 ($V_{cc} = 6.0 \text{ V}$)		

Electrical Characteristics

		Ta =	25°C		Ta = - 85°C	-40 to		Test Co	nditions	
Item	Symbol	Min	Тур	Max	Min	Max	Unit	V _{cc}	•	
Input voltage	V _{IH}	1.5	_	_	1.5	_	V	2.0		
		3.15			3.15	—	_	4.5	-	
		4.2	—	_	4.2	—	_	6.0	-	
	V _{IL}	—	—	0.5	—	0.5	V	2.0		
		—	—	1.35	—	1.35	_	4.5	-	
		—	—	1.8	—	1.8	_	6.0	-	
Output voltage	V_{OH}	1.9	2.0	—	1.9	—	V	2.0	$V_{\rm IN} = V_{\rm IL}$	$I_{OH} = -20 \ \mu A$
		4.4	4.5	_	4.4	—	_	4.5	-	
		5.9	6.0	_	5.9	_	_	6.0	-	
		4.18	4.31		4.31	_	_	4.5	-	I _{OH} = -2 mA
		5.68	5.80		5.63	_	_	6.0	-	I _{OH} = -2.6 mA
	V _{oL}	—	0.0	0.1	—	0.1	V	2.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{oL} = 20 μA
		_	0.0	0.1	_	0.1	_	4.5	-	
		_	0.0	0.1	—	0.1	_	6.0	-	
		_	0.17	0.26	_	0.33	_	4.5	-	I _{oL} = 2 mA
		_	0.18	0.26	_	0.33	_	6.0	-	I _{oL} = 2.6 mA
Input current	I _{IN}	_	_	±0.1	_	±1.0	μA	6.0	$V_{IN} = V_{CC} \text{ or } GN$	1D
Operating current	I _{cc}		_	1.0		10.0		6.0	$V_{IN} = V_{CC}$ or GN	ID

Switching Characteristics

		Ta = 2	25°C				
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Output rise/fall time	t _{TLH}	_	5	10	ns	See Test circuit	
	t _{THL}						
Propagation delay time	t _{PLH}	—	7	15	ns	See Test circuit	
	t _{PHL}						
$(C_{L} = 15 \text{ pF}, t_{r} = t_{f} = 6 \text{ ns}, V_{CC} = 5 \text{ V})$							

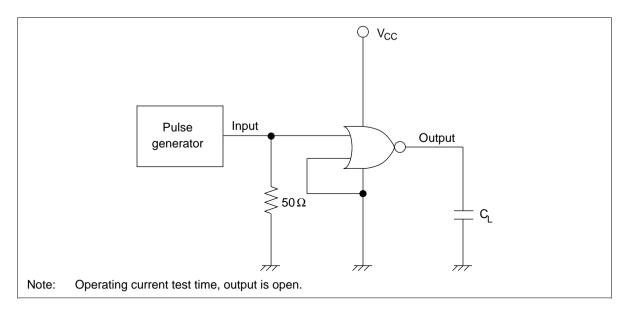
		Ta =	25°C		Ta = 85°C	–40 to		Test C	Conditions
Item	Symbol	Min	Тур	Max	Min	Max	Unit	V _{cc}	_
Output rise/fall time	t_{TLH}		50	125		155	ns	2.0	See Test circuit
	t_{THL}		14	25	_	31	_	4.5	
			12	21		26	_	6.0	
Propagation delay time	t _{PLH}		48	100	_	125	ns	2.0	See Test circuit
	t _{PHL}		12	20	_	25	_	4.5	
			9	17		21	_	6.0	
Input capacitance	CIN		5	10	_	10	pF		
Equivalent capacitance	C _{PD}	_	10				_	_	

 $(C_{L} = 50 \text{ pF}, t_{r} = t_{f} = 6 \text{ ns})$

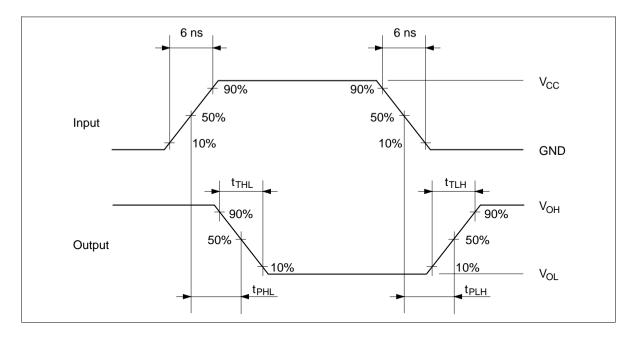
Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

 $I_{cc}(opr) = C_{PD} \bullet V_{cc} \bullet f_{IN} + I_{cc}$

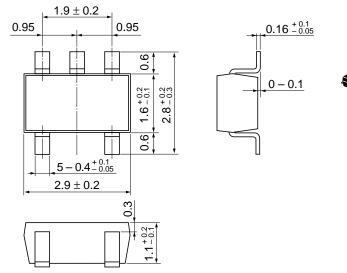
Test Circuit



Waveforms



Unit: mm



Hitachi Code	MPAK-5
JEDEC	—
EIAJ	—
Weight (reference value)	0.015 g

Cautions

- Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as fail-safes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.



Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 NorthAmerica URL http:semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg Europe http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm http://www.hitachi.co.jp/Sicd/indx.htm Japan For further information write to: Hitachi Semiconductor Hitachi Europe GmbH Hitachi Asia Pte. Ltd. (America) Inc. Electronic components Group 16 Collyer Quay #20-00 179 East Tasman Drive, Dornacher Stra§e 3 Hitachi Tower San Jose,CA 95134 D-85622 Feldkirchen, Munich Singapore 049318 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Germany Tel: 535-2100 Tel: <49> (89) 9 9180-0 Fax: 535-1533 Fax: <49> (89) 9 29 30 00

 Fax: <49> (89) 9 29 30 00
 Hita

 Hitachi Europe Ltd.
 Hita

 Electronic Components Group.
 Taip

 Whitebrook Park
 3F,

 Lower Cookham Road
 Tun

 Maidenhead
 Tel:

 Berkshire SL6 8YA, United Kingdom
 Fax

 Tel: <44> (1628) 585000

 Fax: <44> (1628) 778322

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

HITACHI

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.